Internally Compensated, High Performance Operational Amplifier

The MC1741C was designed for use as a summing amplifier, integrator, or amplifier with operating characteristics as a function of the external feedback components.

- No Frequency Compensation Required
- Short Circuit Protection
- Offset Voltage Null Capability
- Wide Common Mode and Differential Voltage Ranges
- Low Power Consumption
- No Latch Up



ON Semiconductor

http://onsemi.com



A = Assembly Location WL, L = Wafer Lot YY, Y = Year WW, W = Work Week



PIN CONNECTIONS



(Top View)

ORDERING INFORMATION

Device	Package	Shipping
MC1741CD	SO–8	98 Units/Rail
MC1741CDR2	2 SO-8	2500 Tape & Reel
MC1741CP1	PDIP-8	50 Units/Rail

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MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Power Supply Voltage	V_{CC}, V_{EE}	±18	Vdc
Input Differential Voltage	V _{ID}	±30	V
Input Common Mode Voltage (Note 1.)	V _{ICM}	±15	V
Output Short Circuit Duration (Note 2.)	t _{SC}	Continuous	-
Operating Ambient Temperature Range	T _A	0 to +70	°C
Storage Temperature Range	T _{stg}	-55 to +125	°C

For supply voltages less than +15 V, the absolute maximum input voltage is equal to the supply voltage.
 Supply voltage equal to or less than 15 V.

ELECTRICAL CHARACTERISTICS (V_{CC} = +15 V, V_{EE} = -15 V, T_A = 25° C, unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
Input Offset Voltage ($R_S \le 10 \text{ k}$)	V _{IO}	-	2.0	6.0	mV
Input Offset Current	I _{IO}	-	20	200	nA
Input Bias Current	I _{IB}	-	80	500	nA
Input Resistance	r _i	0.3	2.0	-	MΩ
Input Capacitance	C _i	-	1.4	-	pF
Offset Voltage Adjustment Range	V _{IOR}	-	±15	-	mV
Common Mode Input Voltage Range	V _{ICR}	±12	±13	-	V
Large Signal Voltage Gain (V _O = ± 10 V, R _L \geq 2.0 k)	A _{VOL}	20	200	-	V/mV
Output Resistance	r _o	-	75	-	Ω
Common Mode Rejection ($R_S \le 10 \text{ k}$)	CMR	70	90	-	dB
Supply Voltage Rejection ($R_S \le 10 \text{ k}$)	PSR	75	-	-	dB
Output Voltage Swing $(R_L \ge 10 \text{ k})$ $(R_L \ge 2.0 \text{ k})$	Vo	±12 ±10	±14 ±13		V
Output Short Circuit Current	I _{SC}	-	20	-	mA
Supply Current	I _D	-	1.7	2.8	mA
Power Consumption	P _C	-	50	85	mW
$ Transient Response (Unity Gain, Noninverting) \\ (V_I = 20 \text{ mV}, \text{R}_L \geq 2.0 \text{k}, \text{C}_L \leq 100 \text{pF}) \text{Rise Time} \\ (V_I = 20 \text{ mV}, \text{R}_L \geq 2.0 \text{k}, \text{C}_L \leq 100 \text{pF}) \text{Overshoot} \\ (V_I = 10 \text{V}, \text{R}_L \geq 2.0 \text{k}, \text{C}_L \leq 100 \text{pF}) \text{Slew Rate} $	t _{TLH} os SR	- - -	0.3 15 0.5	- - -	μs % V/μs

ELECTRICAL CHARACTERISTICS (V_{CC} = +15 V, V_{EE} = -15 V, T_A = T_{low} to T_{high} , unless otherwise noted.)*

Characteristic	Symbol	Min	Тур	Max	Unit
Input Offset Voltage ($R_S \le 10 \text{ k}\Omega$)	V _{IO}	-	-	7.5	mV
Input Offset Current ($T_A = 0^\circ$ to +70°C)	I _{IO}	-	-	300	nA
Input Bias Current (T _A = 0° to +70°C)	I _{IB}	-	-	800	nA
Supply Voltage Rejection ($R_S \le 10 \text{ k}$)	PSR	75	-	-	dB
Output Voltage Swing ($R_L \ge 2.0 \text{ k}$)	V _O	±10	±13	-	V
Large Signal Voltage Gain (R _L \ge 2.0 k, V _O = \pm 10 V)	A _{VOL}	15	-	-	V/mV

* $T_{low} = 0^{\circ}C$ $T_{high} = 70^{\circ}C$



Figure 1. Burst Noise versus Source Resistance



Figure 2. RMS Noise versus Source Resistance



Figure 3. Output Noise versus Source Resistance

Figure 4. Spectral Noise Density



Unlike conventional peak reading or RMS meters, this system was especially designed to provide the quick response time essential to burst (popcorn) noise testing.

The test time employed is 10 sec and the 20 mV peak limit refers to the operational amplifier input thus eliminating errors in the closed loop gain factor of the operational amplifier.

Figure 5. Burst Noise Test Circuit



Figure 8. Positive Output Voltage Swing versus Load Resistance



Figure 10. Output Voltage Swing versus Load Resistance (Single Supply Operation)

Figure 9. Negative Output Voltage Swing versus Load Resistance



Figure 11. Single Supply Inverting Amplifier



Figure 12. Noninverting Pulse Response









PACKAGE DIMENSIONS

PDIP-8 **P1 SUFFIX** CASE 626-05 ISSUE K



NOTES: 1. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL. 2. PACKAGE CONTOUR OPTIONAL (ROUND OR CONTER CONTERPOL

SQUARE CONTOINT OF TOTAL (HOUND OF SQUARE CORNERS). 3. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

	MILLIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
Α	9.40	10.16	0.370	0.400
В	6.10	6.60	0.240	0.260
С	3.94	4.45	0.155	0.175
D	0.38	0.51	0.015	0.020
F	1.02	1.78	0.040	0.070
G	2.54 BSC		0.100	BSC
н	0.76	1.27	0.030	0.050
J	0.20	0.30	0.008	0.012
K	2.92	3.43	0.115	0.135
L	7.62 BSC		0.300	BSC
M		10°		10°
N	0.76	1.01	0.030	0.040

SO-8 **D SUFFIX** CASE 751-06 ISSUE T



NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. DIMENSIONS ARE IN MILLIMETER.
3. DIMENSION D AND E DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
5. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. SHALL BE 0.127 TOTAL IN EXCESS OF THE B DIMENSION AT MAXIMUM MATERIAL CONDITION. CONDITION.

	MILLIMETERS			
DIM	MIN MAX			
Α	1.35	1.75		
A1	0.10	0.25		
В	0.35	0.49		
С	0.19	0.25		
D	4.80	5.00		
Е	3.80	4.00		
е	1.27	1.27 BSC		
Н	5.80	6.20		
h	0.25	0.50		
L	0.40	1.25		
θ	0 °	7 °		

<u>Notes</u>

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